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Interoffice Memorandum

Departmen Miccolis

From Code 300.1

Departmen Sahu 155

Subject 809

Radiation Report on 54AC20LMQB SMEX Common Buy Part No. 5962-87613012A

PPM-91-0692 Date

Nov. 22, 1991

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A radiation evaluation was performed on 54AC20LMQB to determine the total dose tolerance of these parts. A brief summary of the test results is provided below. For detailed information, refer to Tables I through IV and Figure 1.

The total dose testing was performed using a cobalt-60 gamma ray source. During the radiation testing, eight parts were irradiated under bias (see Figure 1 for bias configuration), and two parts were used as control samples. The total dose radiation steps were 10, 20, 30, 50, 75, and 100 krads\*. After 100 krads. parts were annealed at +25°C for 216 hours with measurements taken at 72 and 216 hours. After this annealing, parts were irradiated to 200 krads and, finally, a total accumulated dose of 300 krads, after which they were annealed under bias at +1000c The dose rate was between 0.147 and 5 krads/hour, for 336 hours. depending on the total dose level (see Table II for radiation schedule). After each radiation exposure and annealing treatment, parts were electrically tested @ +25°C according to the test conditions and the specification limits listed in Table These tests included two functional tests at 1 MHz.

All parts passed both functional tests throughout testing to 300 krads. Parts passed all parametric tests and stayed within the specified limits up to 100 krads of irradiation. After 200 krads, 4 parts failed electrical measurements. Two parts failed VOH3, one failed VOH1, and one failed ICCH. After 300 krads of irradiation, 3 parts failed ICCH and ICCL measurements. annealing under bias at +100°C for 336 hours, all parts recovered and passed the final electrical measurements.

Table IV provides a summary of the test results; as well as the mean and standard deviation values for each parameter after different irradiation exposures and annealing steps.

Any further details about this evaluation can be obtained upon request. If you have any questions, please call me at (301) 731-8954.

\*In this report, the term rads is used as an abbreviation for rads (Si).

## TABLE I. Part Information

Generic Part Number: 54AC20IMQB

SMEX Common Buy

Part Number: 5962-87613012A (HA124256)

SMEX Common Buy

Control Number: 2301

Charge Number: C90364

Manufacturer: National Semiconductor

Lot Date Code: 9052A

Quantity Tested: 10

Serial Numbers of

Radiation Samples: 32 - 39

Serial Number of Control Samples:

rol Samples: 30, 31

Part Function: DUAL 4 INPUT NAND GATE

Part Technology: CMOS

Package Style: 20 pin LCC

Test Engineer: R. Tosh

TABLE II. Radiation Schedule for 54AC20LMQB

EV	ENTS	DATE
1)	Initial (Pre-Irradiation) Electrical Measurements	07/31/91
2)	10-KRAD IRRADIATION (0.147 krads/hour) POST 10-KRAD ELECTRICAL MEASUREMENT	09/27/91 09/30/91
3)	20-KRAD IRRADIATION (0.5 krads/hour) POST 20-KRAD ELECTRICAL MEASUREMENT	09/30/91 10/01/91
4)	30-KRAD IRRADIATION (0.5 krads/hour) POST 30-KRAD ELECTRICAL MEASUREMENT	10/01/91 10/02/91
5)	50-KRAD IRRADIATION (930 KRADS/HOUR) POST 50~KRAD ELECTRICAL MEASUREMENT	10/02/91 10/03/91
6)	75-KRAD IRRADIATION (1314.6 KRADS/HOUR) POST 75-KRAD ELECTRICAL MEASUREMENT	10/03/91 10/04/91
7)	100-KRAD IRRADIATION (367.8 KRADS/HOUR) POST 100-KRAD ELECTRICAL MEASUREMENT NOT PERFORMED DUE TO TEST EQUIPMENT (S-50) PROBLEMS	10/04/91
8)	72 HOURS ANNEALING AT +25°C POST 72-HOURS ELECTRICAL MEASUREMENT ANNEALING TIME INCREASED DUE TO S-50 PROBLEMS	10/07/91 10/10/91
9)	216 HOURS ANNEALING AT +25°C POST 216-HOURS ELECTRICAL MEASUREMENT ANNEALING TIME INCREASED DUE TO S-50 PROBLEMS	10/07/91 10/16/91
10)	200-KRAD IRRADIATION (5.0 KRADS/HOUR) POST 200-KRAD ELECTRICAL MEASUREMENTS	10/16/91 10/23/91
11)	300-KRAD IRRADIATION (5.0KRADS/HOUR) POST 300-KRAD ELECTRICAL MEASUREMENTS	10/23/91 10/24/91
12)	336 HOURS ANNEALING AT +100°C UNDER BIAS POST 336 HOURS AT +100°C ELECTRICAL MEASUREMENTS All electrical measurements performed at +25°C.	10/25/91 11/08/91

Electrical Characteristics of 54AC20LMQB Table III.

1							
FUNCT #2	3.ÚV 5.5V	U.UV 3	.UV F	250 = 1MHz 250 = 1MHz		VOL<1.50V	VOX>1.50
RARAMETER VOH1	====	<b>-</b>		CUNSITIONS	PINS		9 +25r-/
YOHZ	۷٠٠٠ ۷٠٠٧ ۲۰۰۷	1.050 3	•15V L	DAD = -500A DAD = -500A DAO = -500A	2100 2100 2100	>2.90V >4.40V	25.50V
VOH4 VDH5 VOH6	3.UV 4.5V 5.5V	1.357 3	.13v L	0A0 = -4MA 0A0 = -24MA	0018 0018 0018	>3.70V	<5.50V <5.50V <5.50V
VOH7	3.5¥	1.057 3	.85∤ ∟	0A0 = -24MA 0A0 = -30MA	5013.	>4.70V	<5.50V
<b>************</b>	7CC 3-0V	VIL U-904.2		CUNDITIONS	PINS		8 +25C
VOL2	4.5V	1.550 3	-15V t.	0à0 ≂ +50jA 0à0 ≈ +50jA	0018 0018 0018	>0.00v	<0.10V <0.10V <0.10V
25355 VOL 5 5-0 VOL 6	3.0V 4.5V 5.5V	1.057 3	.15V L	PAD = +12MA PAD = +24MA PAD = +24MA	0015 0015 0015	>0.00V >0.00V	;
PARAMETER	.ACC	1.02A.2	•obly b	ÁMÓZ+ = CÁO	21nr	>0.00V	· <1.65V
o <del>propo</del> nene Sacolin	3.5V	0.00V 3	==== ±; ->:0v	CONDITIONS ************ Vlm = 5.5V >	PINS	LIMITS:	**======
TIL CCH CCL	5.5V 2.5V 5.5V	ALL IMPLACE	JTS 41	V (N = 3) (3 M	ÍNŠ Vač	> -1.00A > 0.00A > 0.00A > 0.00A	<pre>&lt;+1.00A &lt; 0.00A &lt; 80.04</pre>
· ·							/ < 80 UA
DARAMUT OF	 V. 6			15513 PRUPAG		TIMING:	
PARAMETER	****	ATERA	gata Alu	PINS	. =======	MITS a250	
122 ·	4 - 5 V	0.0v	4 . 5 V	JUT	MIN 1.JNS		MAX 6.0NS
<b>€</b> 2.4 ×	4.5V	0.CV	4.5v	• aut	1.UNS		6. DNS
TPEH-00			4.5√	OUT	1.ons		7.0NS
TERNED1	4 • 5 V	0.07	4.5V	DUT	1.045	•	7.0NS
•			CD	MMENTS/EXCEP	TIONS		

<sup>(1)</sup> FUNCTIONAL TEST #1 WAS PERFORMED WITH ICH= -4.0mA AND IGL=12mA

<sup>(2)</sup> FUNCTIONAL TEST #2 WAS PERFURMED WITH 10H# -24.0mA AND IOL=24mA

CON VAL & VAH WERE TOSTED DURING THE # YOR TESTS AS GOING GO

AL PARAMETERS WERE TESTED AT VCC= 4.5V/ NOT VCC=3.

TABLE IV: Summary of I rical Measurements After
Total Dose Exposures and Annealing for 54AC20LMQB 1/2/

			Total Dose Exposure (TDE) (krads)												l an	Anneal Total Dose (krads)   Anneal						
				<del></del> -				<del></del>	······			<del></del>				· · · · · · · · · · · · · · · · · · ·		Anneal				
	Spec	Limits	•	•			30 50		75		216	216 hrs		200		300		hrs				
Parameters	min		mean		/ mean	вđ	! imean	ad	mean	вđ	ļ maan	44								-		_
FUNC1 0 1 MHz	1	T :		Γ	P		mean.		p		mean	<u>នៅ</u>	mean		mean	sd:	mean	sd.	теал.	sd.	mean	sđ
FUNC2 @ 1 MHz	<del> </del>	<del>                                     </del>	- <b>-</b>		P	<u> </u>	P		<b>b</b>		P	<del></del> -	P		P	<del></del>	P		P		<b>P</b>	
VOH1_3.0V V	2.9	5.5	2.99	0	2.99	0	2.99	70-	2.99	0	2 99	L	2.99	<u> </u>	2.99	- 6	P 3.02	.10	9.00	. 61	₽ 3.00	0
VCH2_4.5V V	4.4	5.5	4,49	0	4.49	0	4_49	0	4.49		4.49	0	4.49		4.49	0	4.56				443 4 3 3 3	
VOH3_5.5V V	5.4	5.5	5.49	-	5.49		5.49	_	5.49	<u> </u>	5.49		5,49	-	5.49	-	5.46	.06	4.49	0	4.49	0
VOH4_3.0V V	2.4	5.5	2.92	0	2,92	Ď	2.92	a	2,92	0	2.92	0	2.92	<del>-</del>	2.92		2.93	.08	5.49 2.92	-	5.49	. 0
VOH5_4.5V V	3.7	5.5	4.19	Ö	4.18	0	4.17	_	4,18	<del></del>	4.17	.01	4.17	.01	4.17	.01	4.19	.08	4.15	0	2.92	0
VOH6_5.5V V	4.7	5.5	5.22	0	5.22	a	5.21	0	5.22		5.21	_	5.21	.01	5.21		5.14	.08	5.20	<del>-</del>	4.15 5.20	.01
VOR7_5.5V V	3.85	5.5	4.90	0	4.89	.01	4.89	.01	4.89		4.88	.01	4.8B	.01	4.B8	.01	4.87	.10	4.86	.01		.01
VOLI_3.0V V	0	0.10	0	_	0.0	_	0	_	0		0		0		0		0		4.80	.0.	4.26	.01_
VOL2_4.5V V	0	0.10	0	_	0		0	_	0		0		O.		0		0		0			
VOL3_5.5V V	٥	0.10	0	_	a	-	. 0		0		0		a	<u> </u>	0		0		0	<del>-</del> -	0	
VOL4_3.0V V	0	0.50	0.129	0	0.130	0	,130	0	129	0	.129	- C	127	0	129	0	.124	0	.121	-	138	.01
VOL5_4.5V V	0	0.50	0.184	0	0.184	0	.185	٥	184		.183	0	.183	0	183	<del>-</del> 0	161	0	.176	Ċ.	.192	
VOL6_5.5V V	0	0.50	9,162	0	0.161	0	162	a .	,162		.162		,162	<u>`</u>	160	0	.159	<u>0</u> -	.155	0	165	.01
VOL7_5.5V V	0	1.55	0.345	0	0.345	.01	.347	.01	.345	0	344	0	.344	.01	344	<u> </u>	338	.01	.331		.355	.01
IIH UA	0	1.0	0	-	0		. 0	-	0		0		0		0	<del>-</del> -	0		0	.01	0	- 02
IIL UA	-1.0	0	0	-	0	-	O.	-	0		0		0		6	-	0	_			0	
ICCH uA	. 0	80.0	0		0	-	.009	.12	.288	.14	,652	.28	1.10	.62	.038				112,81			
ICCL UA	a	80.0	0		e	-	.138	.14	.300	.11	488	.19	,700	. 29	.025				117.74			
TPHL-Q0 nS	1.0	6.0	3.32	0	3.53	.03	3,43	.03	3.68	.05	3,49	.04	3-34	. 04	4.016			_	4.193		4_077	.19
TPHL-Q1 ns	1.0	6.0	3.69	.04	4.93	.05	4.90	.03	4.91		4.92	.05	4.80		4.602	_	<b>6</b> 1956		4.883	<del></del>	4.443	.12
TPLH-Q0 ns	1.0	7.0	5.22	.05	5.29	.03	5.31	.05	5.42	.05	5,47	-	5.46		5.664	-	A	<del></del>	6.225		5.835	.11
TPLH-Q1 ns	1.0	7.0	5.60	.05	6.65	.03	6.66	.04	6.69	.05	6.75	.06	<b>6</b> .68		6.409		32000000		6.116		6.189	.12

## Notes:

<sup>1/</sup> The mean and standard deviation values were calculated over the eight parts irradiated in this testing. The control samples remained constant throughout the testing and are not included in this table.

<sup>2/</sup> Post 72 hour annealing measurements not included in Table IV. This data is available on request.

Figure 1. Radiation Bias Circuit for 54AC20LMQB

